NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE6045XAG uses advanced trench technology and design to provide excellent $R_{\text{DS}(\text{ON})}$ with low gate charge. It can be used in a wide variety of applications.

Application

- Power switching application
- Load switch

General Features

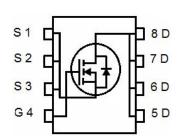
- $V_{DS} = 60V, I_D = 45A$ $R_{DS(ON)} < 9.2m\Omega @ V_{GS} = 10V$ (Typ:8m Ω)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Low gate to drain charge to reduce switching losses

100% UIS TESTED! 100% ΔVds TESTED!

DFN 5X6

Top View

Bottom View



Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
6045XAG	NCE6045XAG	DFN5X6-8L	Ø330mm	12mm	5000

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	60	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	I _D	45	Α
Drain Current-Continuous(T _C =100℃)	I _D (100℃)	32	Α
Pulsed Drain Current	I _{DM}	180	А
Maximum Power Dissipation	P _D	60	W
Derating factor		0.48	W/°C
Single pulse avalanche energy (Note 5)	E _{AS}	260	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	$^{\circ}$

Thermal Characteristic

Thermal Resistance,Junction-to-Case ^(Note 2)	Rejc	2.08	°C/W

NCE6045XAG

Electrical Characteristics (T_C=25°Cunless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2	3	4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =20A	-	8	9.2	mΩ
Forward Transconductance	G FS	V _{DS} =5V,I _D =20A	20	-	-	S
Dynamic Characteristics (Note4)						,
Input Capacitance	C _{lss}	\/ 00\/\/ 0\/	-	2970	-	PF
Output Capacitance	Coss	$V_{DS}=30V, V_{GS}=0V,$	-	181	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	161	-	PF
Switching Characteristics (Note 4)						,
Turn-on Delay Time	t _{d(on)}		-	9	-	nS
Turn-on Rise Time	tr	V_{DD} =30V, R_L =1 Ω	-	7	-	nS
Turn-Off Delay Time	$t_{\sf d(off)}$	V_{GS} =10V, R_{G} =3 Ω	-	32	-	nS
Turn-Off Fall Time	t _f		-	6	-	nS
Total Gate Charge	Qg), oo,,, oo,	-	60		nC
Gate-Source Charge	Q _{gs}	V _{DS} =30V,I _D =20A,	-	14.6		nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	17		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =20A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	45	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 20A	-	31	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	45	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negl	igible (tur	n-on is do	ominated b	y LS+LD)

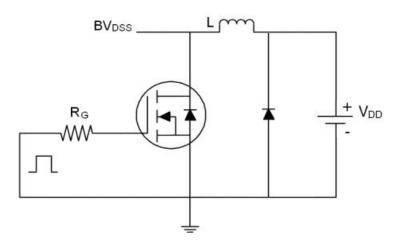
Notes:

- $\textbf{1.} \ \textbf{Repetitive Rating: Pulse width limited by maximum junction temperature}.$
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- **4.** Guaranteed by design, not subject to production

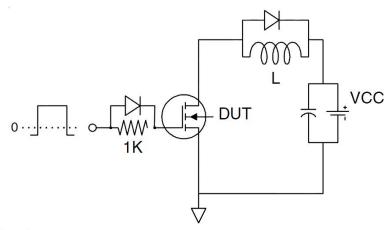
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Test circuit

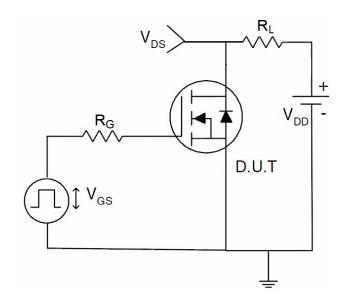
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit



Typical Electrical and Thermal Characteristics (Curves)

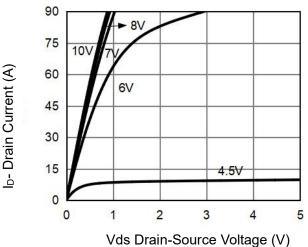
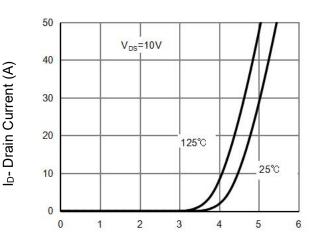


Figure 1 Output Characteristics



Vgs Gate-Source Voltage (V)
Figure 2 Transfer Characteristics

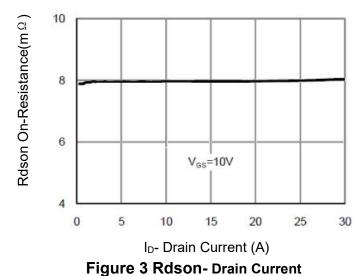


Figure 4 Rdson-JunctionTemperature

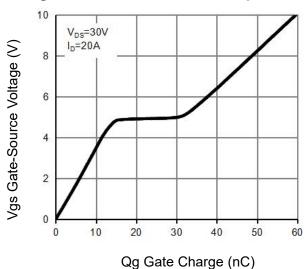


Figure 5 Gate Charge

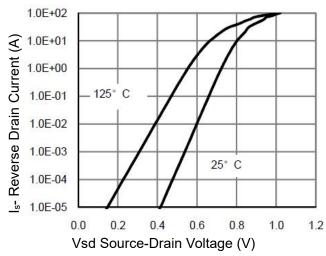


Figure 6 Source- Drain Diode Forward



C Capacitance (pF)

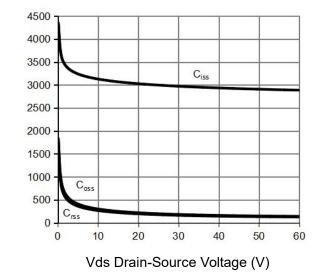


Figure 7 Capacitance vs Vds

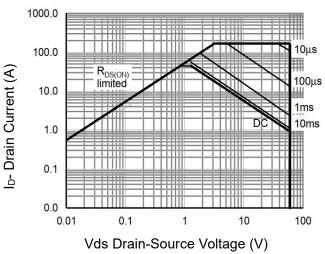
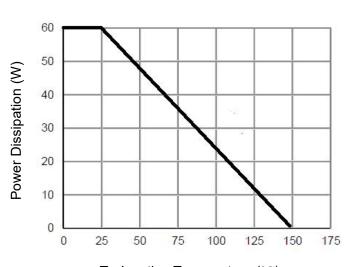


Figure 8 Safe Operation Area



T_J-Junction Temperature (°C) **Figure 9 Power De-rating**

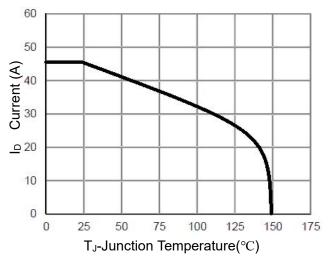
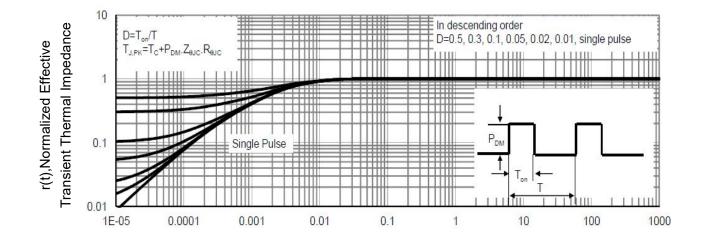


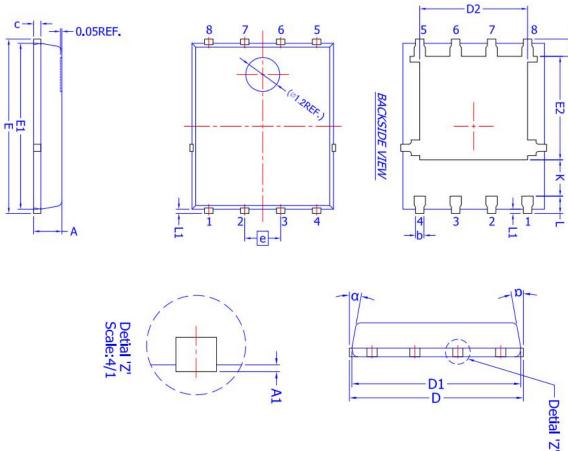
Figure 10ID Current- Junction Temperature



Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance

DFN5X6-8L Package Information



DIM.	MIN.	NOM.	MAX.	
Α	0.90	1.00	1.10	
A1	0	-	0.05	
Ь	0.30	0.40	0.50	
С	0.20	0.25	0.30	
D	5.15 BSC			
D1	5.00 BSC			
D2	3.76	3.86		
Ε	6.15 BSC			
E1	5.80	5.90		
E2	3.45	3.65	3.85	
e	1.27 BSC			
Н	0.51	0.61	0.71	
K	1.10 - 0.51 0.61			
L			0.71	
L1	0.08	0.15	0.23	
α	10°	11°	12°	

NCE6045XAG

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